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# FPAB30BH60

## PFC SPM® 3 Series for Single-Phase Boost PFC

### Features

- UL Certified No. E209204 (UL1557)
- 600 V - 30 A Single-Phase Boost PFC with Integral Gate Driver and Protection
- Very Low Thermal Resistance Using Al<sub>2</sub>O<sub>3</sub> DBC Substrate
- Full-Wave Bridge Rectifier and High-Performance Output Diode
- Built-in NTC Thermistor for Temperature Monitoring
- Optimized for 20kHz Switching Frequency
- Isolation Rating: 2500 Vrms/min.

### Applications

- Single-Phase Boost PFC Converter

### Related Source

- [AN-9090 - PFC SPM 3 Series User's Guide](#)
- [AN-9091 - Boost PFC Inductor Design Guide](#)

### General Description

The FPAB30BH60 is a PFC SPM® 3 module providing a fully-featured, high-performance Boost PFC (Power Factor Correction) input power stage for consumer, medical, and industrial applications. These modules integrate optimized gate drive of the built-in IGBT to minimize EMI and losses, while also providing multiple on-module protection features including under-voltage lockout, over-current shutdown, thermal monitoring, and fault reporting. These modules also feature a full-wave rectifier, and high-performance output diode for additional space savings and mounting convenience

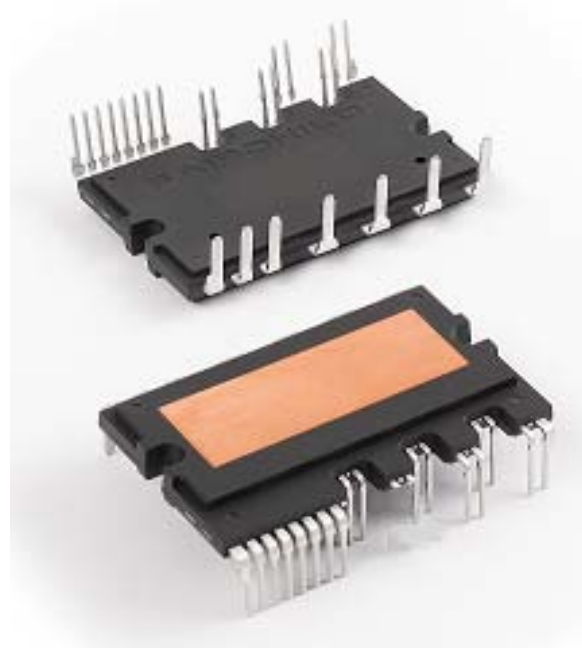


Figure 1. Package Overview

### Package Marking & Ordering Information

Device	Device Marking	Package	Packing Type	Quantity
FPAB30BH60	FPAB30BH60	SPMIA-027	Rail	10

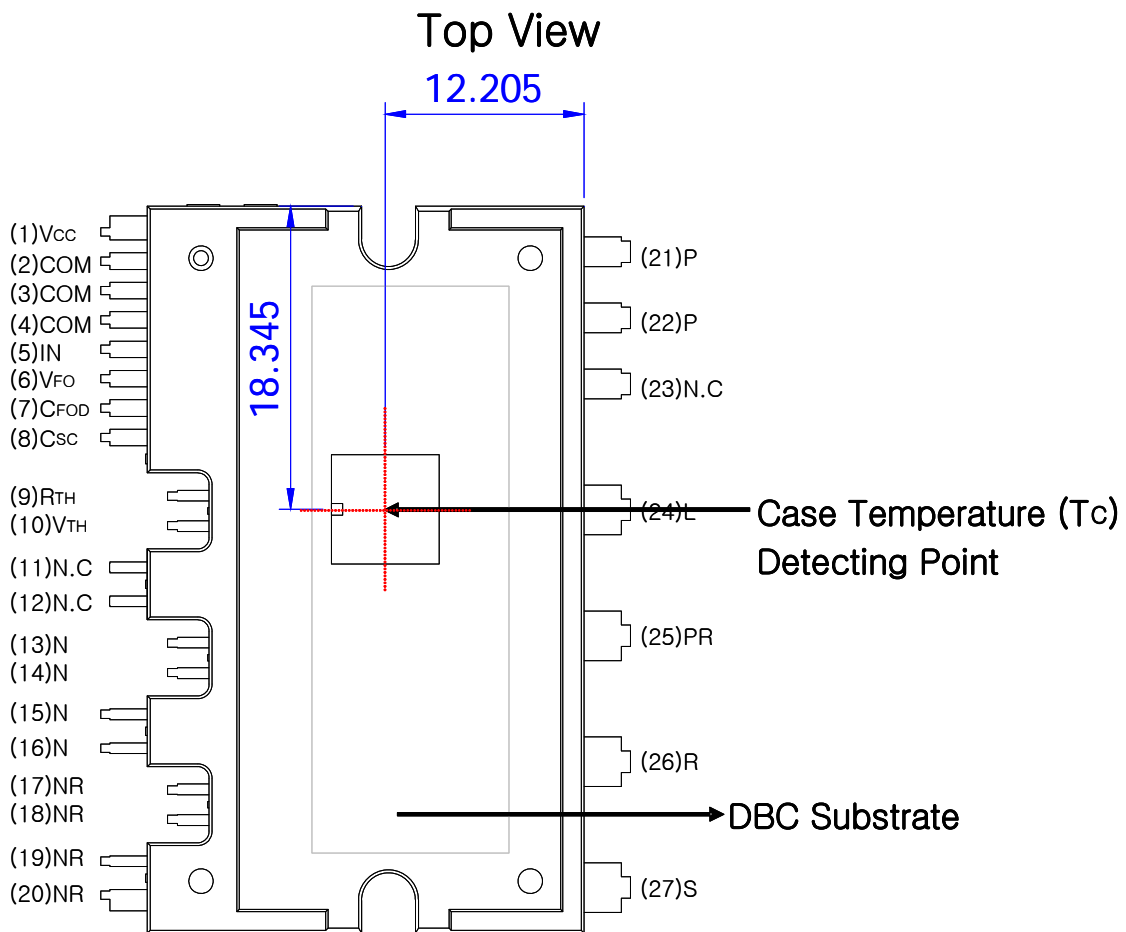
### Integrated Power Functions

- PFC converter for single-phase AC / DC power conversion (please refer to Figure 3)

### Integrated Drive, Protection, and System Control Functions

- For IGBTs: gate drive circuit, Over-Current Protection (OCP), control supply circuit Under-Voltage Lock-Out (UVLO) Protection
- Fault signal: corresponding to OC and UV fault
- Built-in thermistor: temperature monitoring
- Input interface: active-HIGH interface, works with 3.3 / 5 V logic, Schmitt-trigger input

### Pin Configuration



**Figure 2. Top View**

**Notes :**

1. For the measurement point of case temperature(T<sub>c</sub>), please refer to Figure 2.

## Pin Descriptions

Pin Number	Pin Name	Pin Description
1	V <sub>CC</sub>	Common Bias Voltage for IC and IGBT Driving
2,3,4	COM	Common Supply Ground
5	IN	Signal Input for IGBT
6	V <sub>FO</sub>	Fault Output
7	C <sub>FOD</sub>	Capacitor for Fault Output Duration Selection
8	C <sub>SC</sub>	Capacitor (Low-Pass Filter) for Over-Current Detection
9	R <sub>(TH)</sub>	Series Resistor for The Use of Thermistor
10	V <sub>(TH)</sub>	Thermistor Bias Voltage
11,12	N.C	No Connection*
13~16	N	IGBT Emitter
17~20	N <sub>R</sub>	Negative DC-Link of Rectifier
21,22	P	Positive Rail of DC-Link
23	N.C	No Connection
24	L	Reactor Connection Pin
25	P <sub>R</sub>	Positive DC-Link of Rectifier
26	R	AC Input for R-Phase
27	S	AC Input for S-Phase

\* 11th and 12th pins are cut. Please refer to package outline drawings for more detail.

## Internal Equivalent Circuit and Input/Output Pins

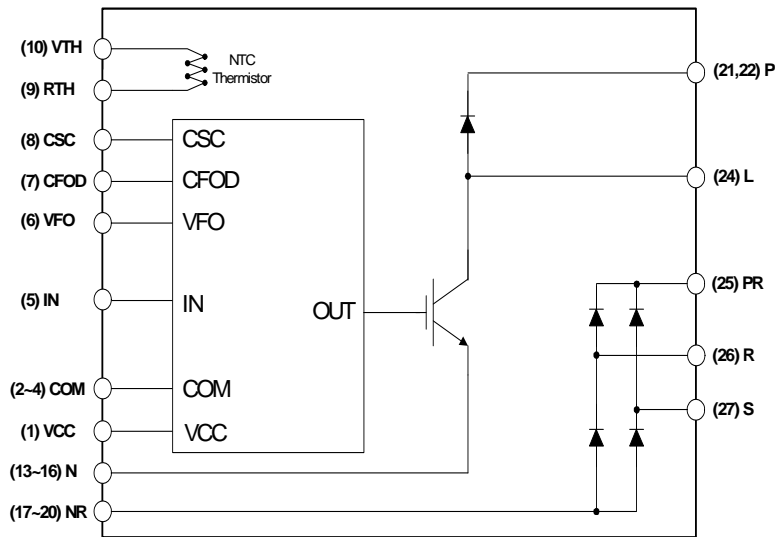


Figure 3. Internal Block Diagram

**Absolute Maximum Ratings** ( $T_J = 25^\circ\text{C}$ , unless otherwise specified.)**Converter Part**

Symbol	Item	Condition	Rating	Unit
$V_i$	Supply Voltage	Applied between R - S	264	$V_{\text{rms}}$
$V_{i(\text{Surge})}$	Supply Voltage (Surge)	Applied between R - S	500	V
$V_{\text{PN}}$	Output Voltage	Applied between P - N	450	V
$V_{\text{PN}(\text{Surge})}$	Output Voltage (Surge)	Applied between P - N	500	V
$V_{\text{CES}}$	Collector - Emitter Voltage		600	V
$I_{\text{FSM}}$	Peak Forward Surge Current	Single Half Sine-Wave	250	A
$I_i$	Input Current (100% Load)	$T_C < 95^\circ\text{C}$ , $V_i = 220\text{ V}$ , $V_{\text{PN}} = 390\text{ V}$ , $V_{\text{PWM}} = 20\text{ kHz}$	25	A
$I_{i(125\%)}$	Input Current (125% Load)	$T_C < 95^\circ\text{C}$ , $V_i = 220\text{ V}$ , $V_{\text{PN}} = 390\text{ V}$ , $V_{\text{PWM}} = 20\text{ kHz}$ , 1 Minute Non-Repetitive	30	A
$P_C$	Collector Dissipation	$T_C = 25^\circ\text{C}$	169	W
$T_J$	Operating Junction Temperature		-20 ~ 150	$^\circ\text{C}$

**Notes:**

1. The maximum junction temperature rating of the power chips integrated within the PFC SPM® product is  $150^\circ\text{C}$  ( $@T_C \leq 100^\circ\text{C}$ ). However, to insure safe operation of the PFC SPM product, the average junction temperature should be limited to  $T_{J(\text{ave})} \leq 125^\circ\text{C}$  ( $@T_C \leq 100^\circ\text{C}$ )

**Control Part**

Symbol	Item	Condition	Rating	Unit
$V_{\text{CC}}$	Control Supply Voltage	Applied between $V_{\text{CC}}$ - COM	20	V
$V_{\text{IN}}$	Input Signal Voltage	Applied between IN - COM	-0.3 ~ $V_{\text{CC}}+0.3$	V
$V_{\text{FO}}$	Fault Output Supply Voltage	Applied between $V_{\text{FO}}$ - COM	-0.3 ~ $V_{\text{CC}}+0.3$	V
$I_{\text{FO}}$	Fault Output Current	Sink Current at $V_{\text{FO}}$ Pin	5	mA
$V_{\text{SC}}$	Current Sensing Input Voltage	Applied between $C_{\text{SC}}$ - COM	-0.3 ~ $V_{\text{CC}}+0.3$	V

**Total System**

Symbol	Item	Condition	Rating	Unit
$T_C$	Module Case Operating Temperature		-20 ~ 100	$^\circ\text{C}$
$T_{\text{STG}}$	Storage Temperature		-40 ~ 125	$^\circ\text{C}$
$V_{\text{ISO}}$	Isolation Voltage	60 Hz, Sinusoidal, AC 1 Minute, Connect Pins to Heat Sink Plate	2500	$V_{\text{rms}}$

**Thermal Resistance**

Symbol	Item	Condition	Min.	Typ.	Max.	Unit
$R_{\theta(j-c)Q}$	Junction to Case Thermal Resistance	IGBT	-	-	0.74	$^\circ\text{C}/\text{W}$
$R_{\theta(j-c)F}$		FRD	-	-	1.44	$^\circ\text{C}/\text{W}$
$R_{\theta(j-c)R}$		Rectifier (per 1 / 4 module)	-	-	2.07	$^\circ\text{C}/\text{W}$

**Notes:**

2. For the measurement point of case temperature( $T_C$ ), please refer to Figure 2.

### Electrical Characteristics (T<sub>J</sub> = 25°C, Unless Otherwise Specified.)

#### Converter Part

Symbol	Item	Condition	Min.	Typ.	Max.	Unit
V <sub>CE(SAT)</sub>	IGBT Saturation Voltage	V <sub>CC</sub> = 15 V, V <sub>IN</sub> = 5 V, I <sub>C</sub> = 30 A	-	2.0	2.8	V
V <sub>FF</sub>	FRD Forward Voltage	I <sub>F</sub> = 30 A	-	1.8	2.5	V
V <sub>FR</sub>	Rectifier Forward Voltage	I <sub>F</sub> = 30 A	-	1.2	1.5	V
t <sub>ON</sub>	Switching Times	V <sub>PN</sub> = 400 V, V <sub>CC</sub> = 15V, I <sub>C</sub> = 30 A V <sub>IN</sub> = 0 V ↔ 5 V, Inductive Load (Note 3)	-	650	-	ns
t <sub>C(ON)</sub>			-	400	-	ns
t <sub>OFF</sub>			-	620	-	ns
t <sub>C(OFF)</sub>			-	200	-	ns
t <sub>rr</sub>			-	60	-	ns
I <sub>rr</sub>			-	3.5	-	A
I <sub>CES</sub>	Collector - Emitter Leakage Current	V <sub>CE</sub> = V <sub>CES</sub>	-	-	250	μA

**Notes:**

3. t<sub>ON</sub> and t<sub>OFF</sub> include the propagation delay time of the internal drive IC. t<sub>C(ON)</sub> and t<sub>C(OFF)</sub> are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Figure 4.

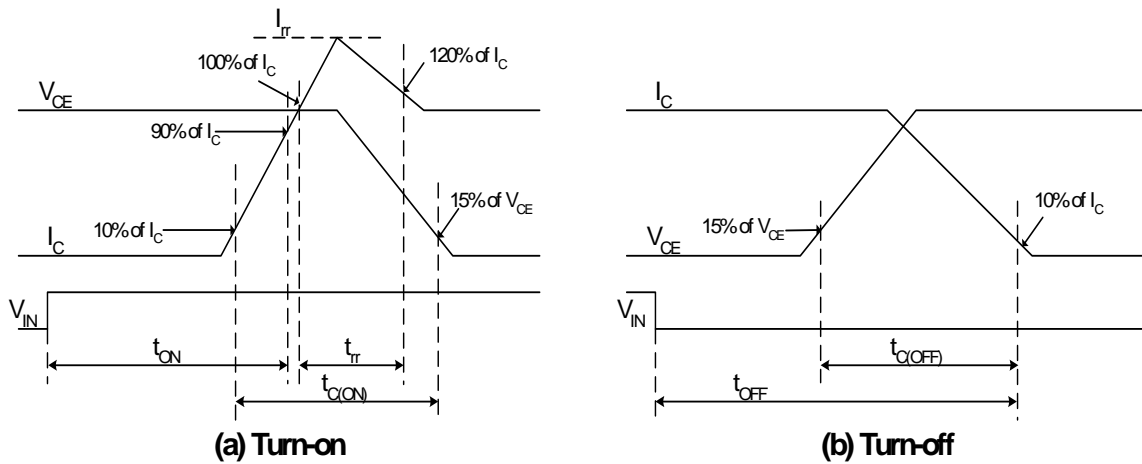


Figure 4. Switching Time Definition

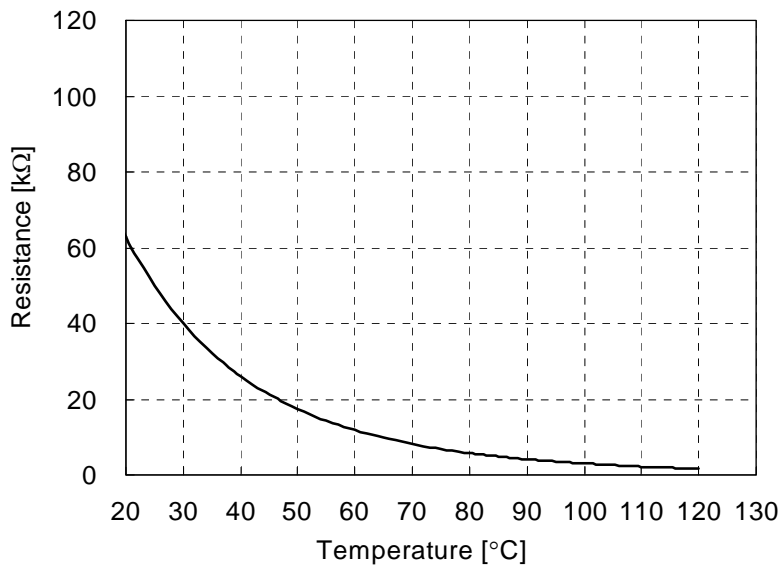
**Control Part**

Symbol	Item	Condition	Min.	Typ.	Max.	Unit
I <sub>QCCL</sub>	Quiescent V <sub>CC</sub> Supply Current	V <sub>CC</sub> = 15 V, IN = 0 V   V <sub>CC</sub> - COM	-	-	26	mA
V <sub>FOH</sub>	Fault Output Voltage	V <sub>SC</sub> = 0 V, V <sub>FO</sub> Circuit: 4.7 kΩ to 5 V Pull-up	4.5	-	-	V
V <sub>FOL</sub>		V <sub>SC</sub> = 1 V, V <sub>FO</sub> Circuit: 4.7 kΩ to 5 V Pull-up	-	-	0.8	V
V <sub>SC(ref)</sub>	Over-Current Trip Level	V <sub>CC</sub> = 15 V	0.45	0.5	0.55	V
UV <sub>CCD</sub>	Supply Circuit Under-Voltage Protection	Detection Level	10.7	11.9	13.0	V
UV <sub>CCR</sub>		Reset Level	11.2	12.4	13.2	V
t <sub>FOD</sub>	Fault-Out Pulse Width	C <sub>FOD</sub> = 33 nF (Note 3)	1.4	1.8	2.0	ms
V <sub>IN(ON)</sub>	ON Threshold Voltage	Applied between IN - COM	2.8	-	-	V
V <sub>IN(OFF)</sub>	OFF Threshold Voltage		-	-	0.8	V
R <sub>TH</sub>	Resistance of Thermistor	at T <sub>TH</sub> = 25°C (Note 4, Figure 5)	-	50	-	kΩ
		at T <sub>TH</sub> = 100°C (Note 4, Figure 5)	-	2.99	-	kΩ

**Notes:**

3. The fault-out pulse width t<sub>FOD</sub> depends on the capacitance value of C<sub>FOD</sub> according to the following approximate equation : C<sub>FOD</sub> = 18.3 x 10<sup>-6</sup> x t<sub>FOD</sub>[F]
4. T<sub>TH</sub> is the temperature of know case temperature(T<sub>C</sub>), please make the experiment considering your application.

R-T Graph



**Figure 5. R-T Curve of the Built-In Thermistor**

### Recommended Operating Condition

Symbol	Item	Condition	Min.	Typ.	Max.	Unit
$V_i$	Input Supply Voltage	Applied between R - S	187	220	253	$V_{rms}$
$V_{PN}$	Output Voltage	Applied between P - N	-	380	400	V
$V_{CC}$	Control Supply Voltage	Applied between $V_{CC(L)}$ - COM	13.5	15.0	16.5	V
$dV_{CC}/dt$	Control Supply Variation		-1	-	1	V/ $\mu$ s
$f_{PWM}$	PWM Input Frequency	$T_J \leq 150^\circ\text{C}$	-	20	-	kHz
$I_i$	Allowable Input Current	$T_C < 90^\circ\text{C}$ , $V_i = 220\text{ V}$ , $V_{PN} = 380\text{ V}$ $V_{PWM} = 20\text{ kHz}$	-	-	30	$A_{peak}$

### Mechanical Characteristics and Ratings

Item	Condition		Min.	Typ.	Max.	Unit
Mounting Torque	Mounting Screw: M3	Recommended 0.62 N•m	0.51	0.62	0.72	N•m
Device Flatness	See Figure 6		0	-	+120	$\mu$ m
Weight			-	15.00	-	g

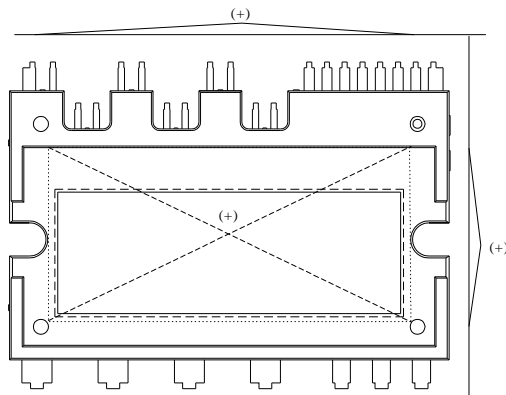
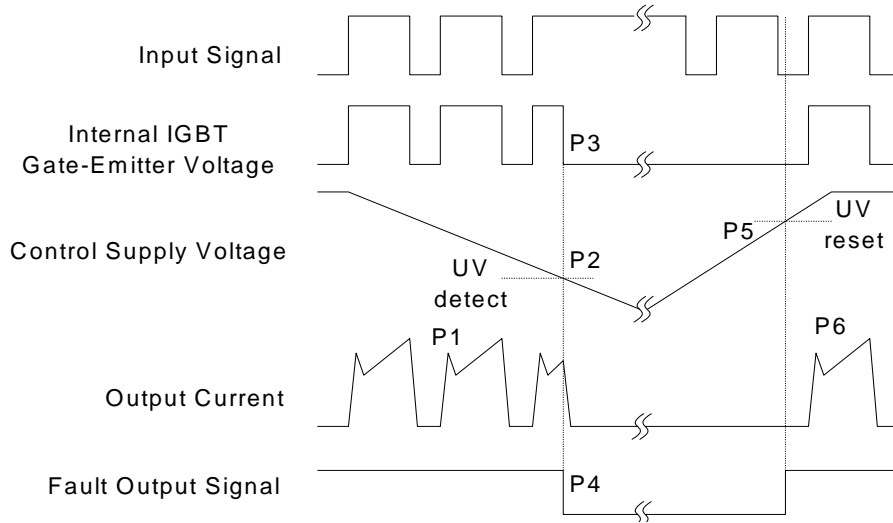


Figure 6. Flatness Measurement Position

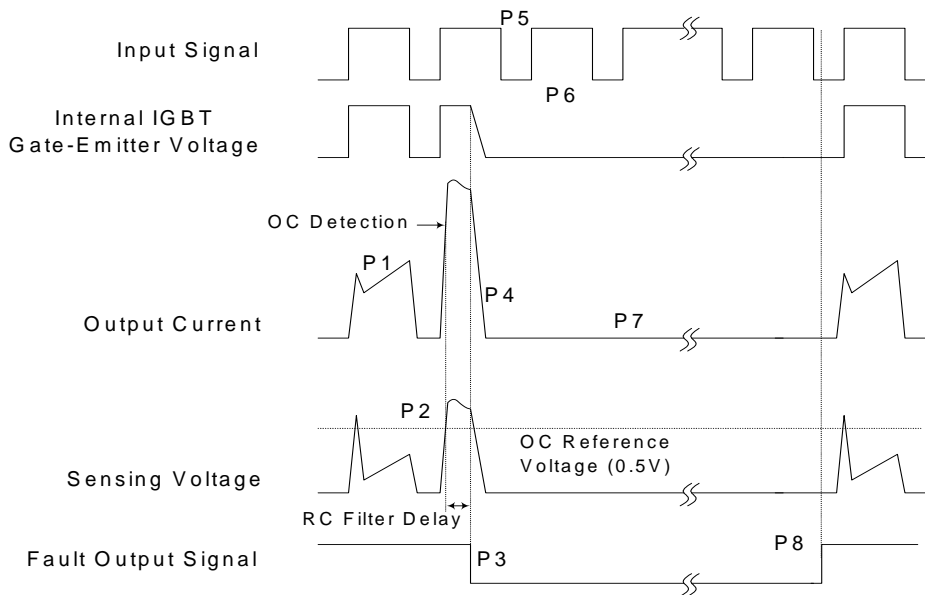


### Time Charts of Protective Function



- P1 : Normal operation: IGBT ON and conducting current
- P2 : Under-voltage detection
- P3 : IGBT gate interrupt
- P4 : Fault signal generation
- P5 : Under-voltage reset
- P6 : Normal operation: IGBT ON and conducting current

**Figure 7. Under-Voltage Protection**



- P1 : Normal operation: IGBT ON and conducting current
- P2 : Over current detection
- P3 : IGBT gate interrupt / fault signal generation
- P4 : IGBT is slowly turned off
- P5 : IGBT OFF signal
- P6 : IGBT ON signal: but IGBT cannot be turned on during the fault output activation
- P7 : IGBT OFF state
- P8 : Fault output reset and normal operation start

**Figure 8. Over-Current Protection**

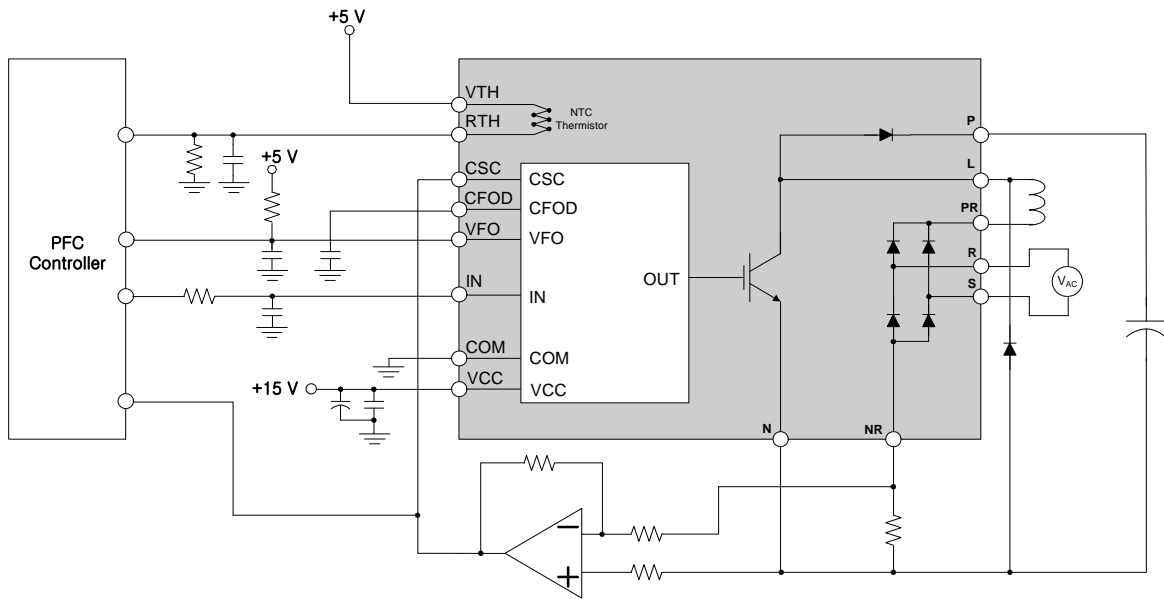
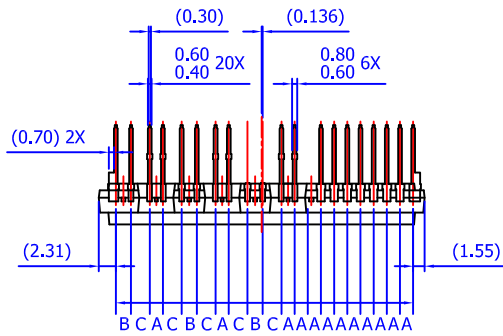


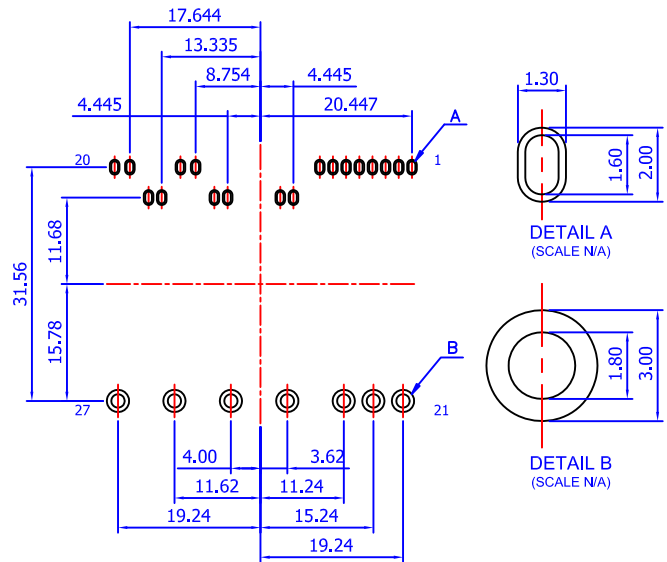
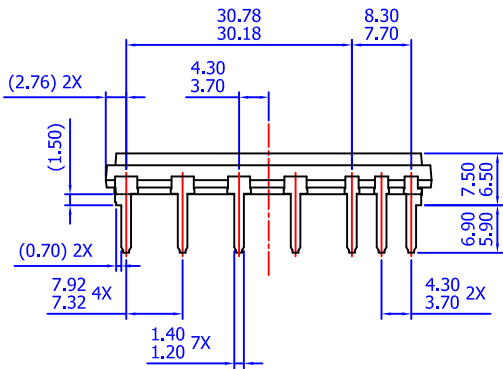
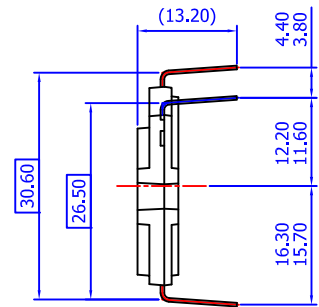
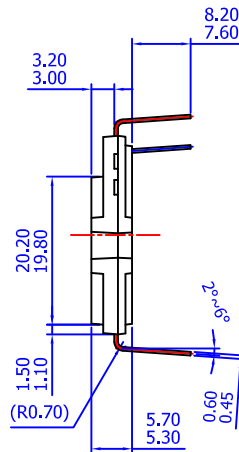
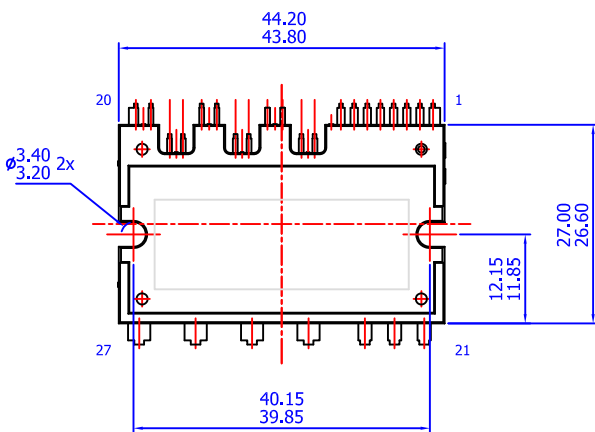
Figure 9. Application Example

Notes:

- 5. Each capacitors should be located as close to PFC SPM® product pins as possible.
- 6. It's recommended that anti-parallel diode should be connected with IGBT.



LEAD PITCH (TOLERANCE : ±0.30)  
 A : 1.778  
 B : 2.050  
 C : 2.531



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- QS™
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- ™
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- SmartMax™
- SMART START™
- Solutions for Your Success™
- SPM®
- STEALTH™
- SuperFET®
- SuperSOT™-3
- SuperSOT™-6
- SuperSOT™-8
- SupreMOS®
- SyncFET™
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